

Surface Mount Ultrafast Avalanche Rectifiers

AU1PD, AU1PG, AU1PJ AU1PK, AU1PM

Vishaymas General Semiconductor



DO-220AA (SMP)

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	1.0 A
V_{RRM}	200 V, 400 V, 600 V, 800 V, 1000 V
I_{FSM}	30 A, 25 A
t_{rr}	75 ns
I_R	1 μ A
E_{AS}	20 mJ
V_F at $I_F = 1.0$ A	1.6 V
T_J max.	175 °C
Package	DO-220AA (SMP)
Diode variations	Single die

FEATURES

- Very low profile - typical height of 1.0 mm
- Ideal for automated placement
- Glass passivated pellet chip junction
- Ultrafast recovery times for high frequency
- Low reverse current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishaymas.com

MECHANICAL DATA

Case: DO-220AA (SMP)

Molding compound meets UL 94 V-0 flammability rating
Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and automotive grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

TYPICAL APPLICATIONS

For use in secondary rectification and freewheeling for ultrafast switching speeds of AC/AC and DC/DC converters in high temperature conditions for both consumer and automotive applications.

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	AU1PD	AU1PG	AU1PJ	AU1PK	AU1PM	UNIT
Device marking code		AUD	AUG	AUJ	AUK	AUM	
Maximum repetitive peak reverse voltage	V _{RRM}	200	400	600	800	1000	V
Average forward current	I _{F(AV)}	1.0					A
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	30			25		A
Non-repetitive avalanche energy at I _{AS} = 1.0 A, T _A = 25 °C	E _{AS}	20					mJ
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +175					°C

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)									
PARAMETER	TEST CONDITIONS		SYMBOL	AU1PD	AU1PG	AU1PJ	AU1PK	AU1PM	UNIT
Maximum instantaneous forward voltage	I _F = 1.0 A	T _A = 25 °C	V _F ⁽¹⁾	1.5			1.85		V
		T _A = 125 °C		1.4			1.6		
Maximum reverse current	Rated V _R	T _A = 25 °C	I _R ⁽²⁾	1.0					μA
		T _A = 125 °C		100					
Maximum reverse recovery time	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A		t _{rr}	75					ns
Typical junction capacitance	4.0 V, 1 MHz		C _J	11			7.5		pF

Notes

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS (T _A = 25 °c unless otherwise noted)							
PARAMETER	SYMBOL	AU1PD	AU1PG	AU1PJ	AU1PK	AU1PM	UNIT
Typical thermal resistance	R _{θJA} ⁽¹⁾	132					°C/W
	R _{θJM} ⁽¹⁾	15					

Note

(1) Free air, mounted on recommended copper pad area. Thermal resistance $R_{\theta JA}$ - junction to ambient, $R_{\theta JM}$ - junction to mount at the terminal cathode band

ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
AU1PJ-M3/84A	0.024	84A	3000	7" diameter plastic tape and reel
AU1PJ-M3/85A	0.024	85A	10 000	13" diameter plastic tape and reel
AU1PJHM3/84A ⁽¹⁾	0.024	84A	3000	7" diameter plastic tape and reel
AU1PJHM3/85A ⁽¹⁾	0.024	85A	10 000	13" diameter plastic tape and reel

Note

(1) Automotive grade

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25^\circ\text{C}$ unless otherwise noted)

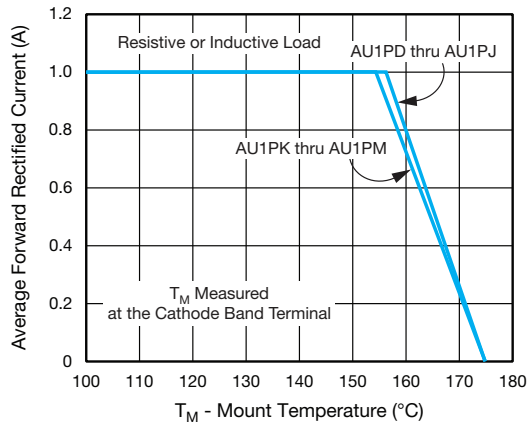


Fig. 1 - Maximum Forward Current Derating Curve

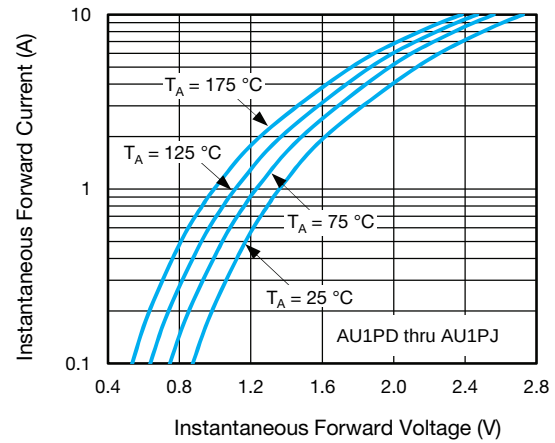


Fig. 4 - Typical Instantaneous Forward Characteristics

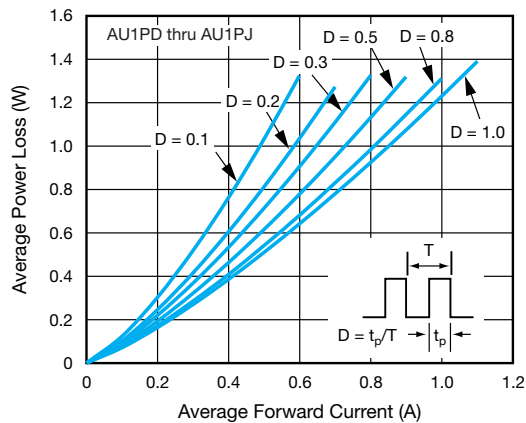


Fig. 2 - Forward Power Loss Characteristics

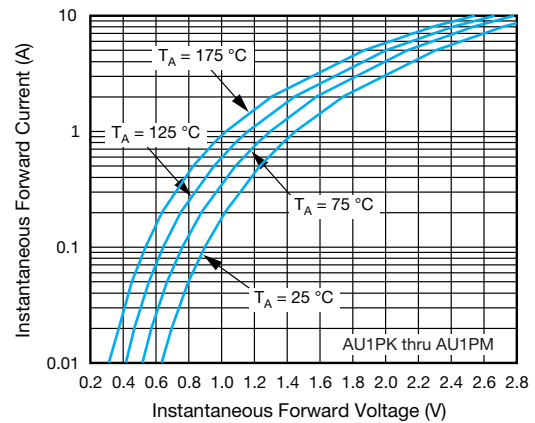


Fig. 5 - Typical Instantaneous Forward Characteristics

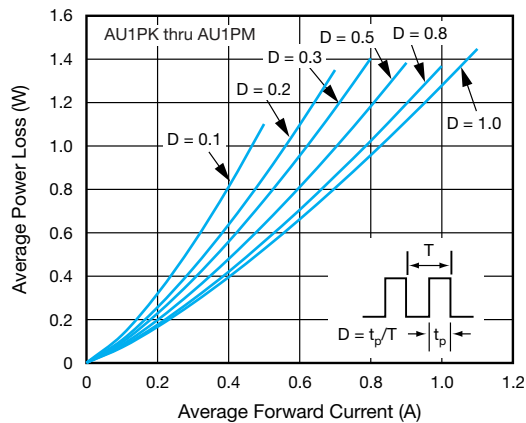


Fig. 3 - Forward Power Loss Characteristics

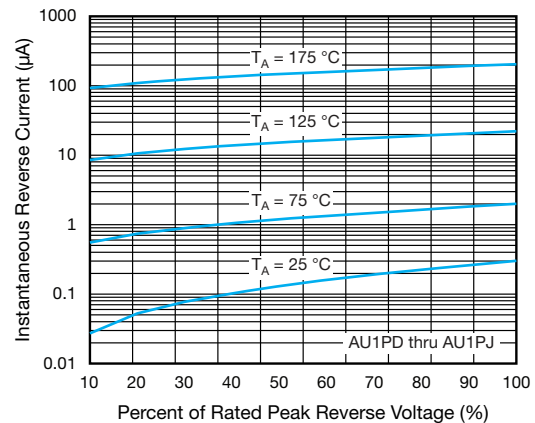


Fig. 6 - Typical Reverse Characteristics

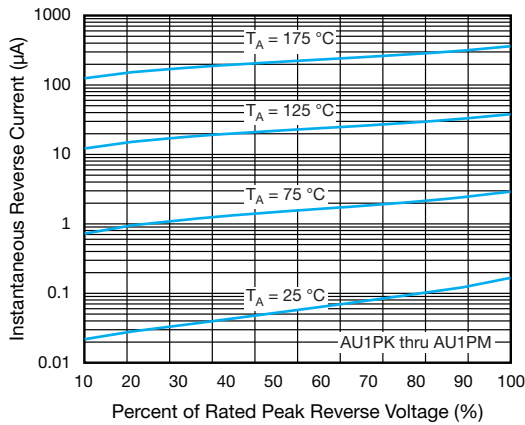


Fig. 7 - Typical Reverse Characteristics

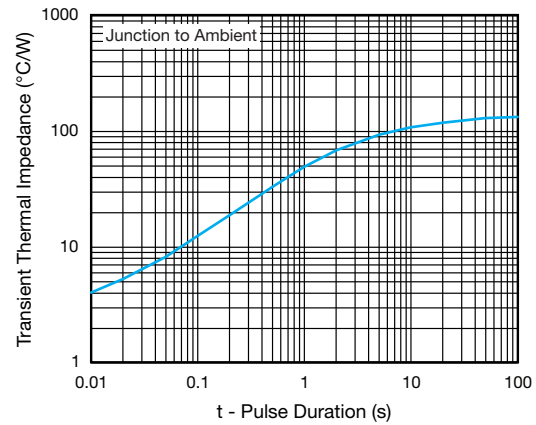


Fig. 9 - Typical Transient Thermal Impedance

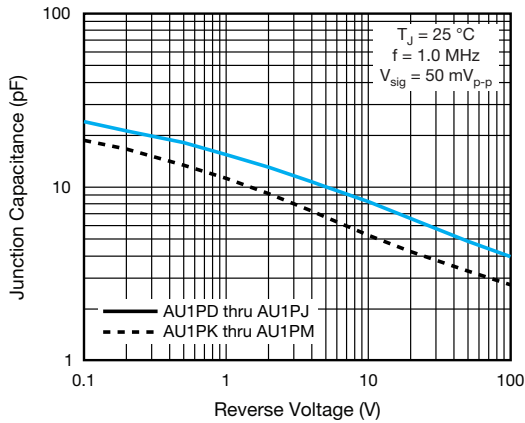


Fig. 8 - Typical Junction Capacitance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-220AA (SMP)

